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# HL6712G

AlGaInP Laser Diode

# HITACHI

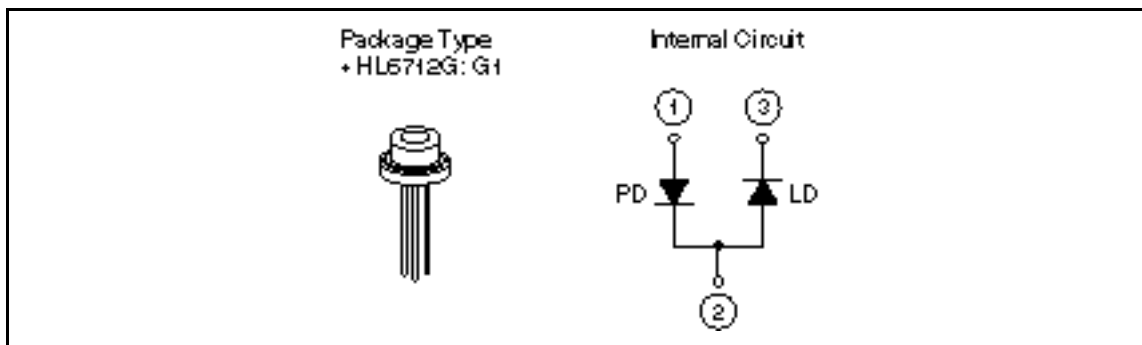
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## Description

The HL6712G is 0.67  $\mu\text{m}$  band AlGaInP index-guided laser diode with a double heterostructure. It is suitable as light sources for barcode readers, levelers, laser printers, and various other types of optical equipment. Hermetic sealing of the packages assure high reliability.

## Features

- Visible light output at wavelengths up to 680 nm
- Single longitudinal mode
- Low threshold current: 40 mA Typ
- Low astigmatism: 10  $\mu\text{m}$  Typ
- Operates at temperatures up to 50°C
- Built-in monitor photodiode



## HL6712G

### Absolute Maximum Ratings ( $T_C = 25^\circ\text{C}$ )

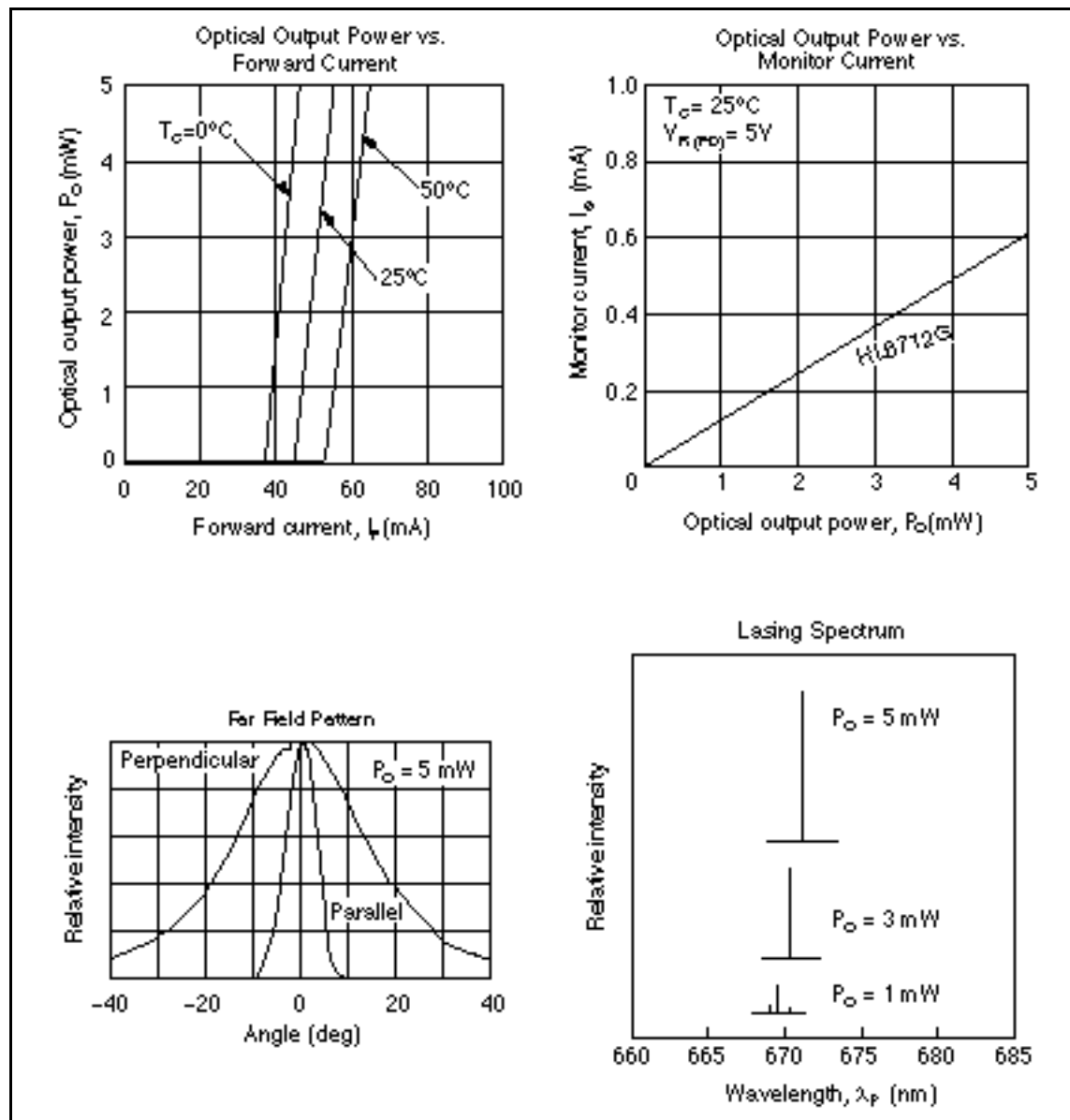
Item	Symbol	Rated Value	Unit
Optical output power	$P_O$	5	mW
Pulse optical output power	$P_{O(pulse)}$	6* <sup>1</sup>	mW
LD reverse voltage	$V_{R(LD)}$	2	V
PD reverse voltage	$V_{R(PD)}$	30	V
Operating temperature	$T_{opr}$	-10 to +50	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-40 to +85	$^\circ\text{C}$

Note: 1. Maximum 50% duty cycle, maximum 1 $\mu\text{s}$  pulse width

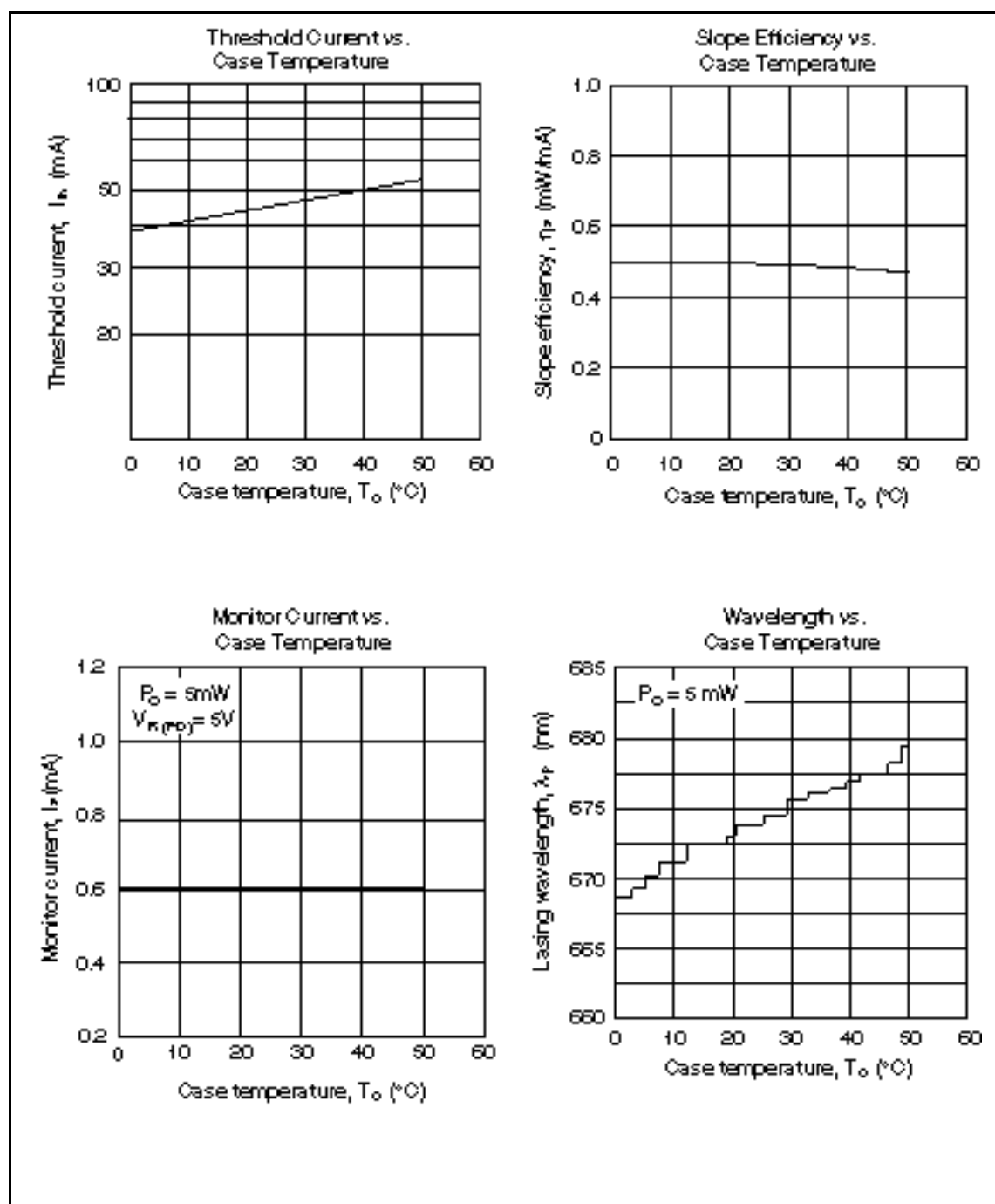
### Optical and Electrical Characteristics ( $T_C = 25^\circ\text{C}$ )

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Optical output power	$P_O$	5	—	—	mW	Kink free
Threshold current	$I_{th}$	—	40	65	mA	
Slope efficiency		0.3	0.55	0.7	mW/mA	$3 \text{ mW}/I_{(4 \text{ mW})} - I_{(1 \text{ mW})}$
Lasing wavelength	$\lambda$	660	670	680	nm	$P_O = 5 \text{ mW}$
Beam divergence (parallel)	//	5	8	11	deg.	$P_O = 5 \text{ mW}$ , FWHM
Beam divergence (perpendicular)		22	27	37	deg.	$P_O = 5 \text{ mW}$ , FWHM
Monitor current	$I_s$	0.25	0.6	1.25	mA	$P_O = 5 \text{ mW}$ , $V_{R(PD)} = 5 \text{ V}$
Astigmatism	$A_s$	—	10	—	$\mu\text{m}$	$P_O = 5 \text{ mW}$ , NA = 0.4

# Typical Characteristic Curves



Typical Characteristic Curves (cont)



Typical Characteristic Curves (cont)

